Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-030-4410

Inclosure Material:

Ceramic or plastic

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

1.9 watts small-signal input power, common-collector absolute all transistor

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

14 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0